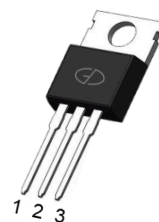


## N-Channel 60V (D-S) Power MOSFET

### Features

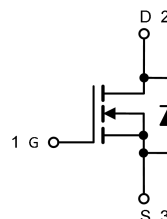
- 100% Avalanche Tested
- Extremely Low Losses with Low FOM  $R_{DS(on)} \cdot Q_g$
- Halogen Free, Pb-Free
- RoHS Compliant



TO-220AB

### Applications

- DC/DC
- Motors, lamps
- Power switching



### Absolute Maximum Ratings ( $T_J=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain Source Voltage	$V_{DS}$	60	V
Gate Source Voltage	$V_{GS}$	$\pm 20$	V
Drain Current, Continuous $V_{GS}=10\text{V}$ (Note 1)	$I_D$	80	A
Drain Current, Pulsed (Note 2)	$I_{DM}$	320	A
Single Avalanche Energy @ $L=0.5\text{mH}$	$E_{AS}$	206	mJ
Avalanche Current	$I_{AS}$	28.6	A
Power Dissipation (Note 3)	$P_D$	205	W
Operating Junction/ Storage Temperature Range	$T_J / T_{STG}$	-55 to +150	$^\circ\text{C}$

Note 1: Calculated continuous current based on maximum allowable junction temperature.

Note 2: Repetitive rating; pulse width limited by max. junction temperature.

### Thermal Characteristics

Parameter	Symbol	Max	Unit
Thermal Resistance Junction to Case(Note 3)	$R_{thJC}$	0.61	$^\circ\text{C/W}$

Note 3: The power dissipation  $P_D$  is based on max. junction temperature, using junction-to-case thermal resistance.

## Electrical Characteristics (T<sub>J</sub> = 25°C unless otherwise noted)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Drain Source Breakdown Voltage	V <sub>(BR)DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250μA	60	--	--	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =60V, V <sub>GS</sub> =0V	--	--	1	uA
Gate Threshold Voltage	V <sub>GS(TH)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>DS</sub> =250uA	2	--	4	V
Gate Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V	--	--	±100	nA
Drain-Source On-state Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =20A	--	6.5	8	mΩ
Total Gate Charge	Q <sub>g</sub>	I <sub>D</sub> = 20A, V <sub>DS</sub> =30V, V <sub>GS</sub> = 10V	--	70	--	nC
Gate-Source Charge	Q <sub>gs</sub>		--	15	--	
Gate-Drain Charge	Q <sub>gd</sub>		--	20	--	
Turn-on Delay Time	t <sub>d(on)</sub>	V <sub>GS</sub> =10V, V <sub>DS</sub> =30V, R <sub>GEN</sub> =3Ω I <sub>D</sub> = 30A	--	16	--	ns
Turn-on Rise Time	t <sub>r</sub>		--	23	--	
Turn-off Delay Time	t <sub>d(off)</sub>		--	44	--	
Turn-off Fall Time	t <sub>f</sub>		--	13	--	
Input Capacitance	C <sub>iss</sub>	V <sub>GS</sub> =0V, V <sub>DS</sub> =60V, f=1MHz	--	3420	--	pF
Output Capacitance	C <sub>oss</sub>		--	163	--	
Reverse Transfer Capacitance	C <sub>rss</sub>		--	153	--	

## Reverse Diode Characteristics (T<sub>J</sub> = 25°C unless otherwise noted)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Continuous Source Current (Body Diode)	I <sub>S</sub>	T <sub>C</sub> =25°C	--	--	80	A
Pulsed Source Current (Body Diode)	I <sub>SM</sub>		--	--	320	
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =20A, V <sub>GS</sub> =0V	--	--	1.2	V
Reverse Recovery Time	T <sub>rr</sub>	I <sub>S</sub> =20A, di/dt = 100 A/μs	--	25	--	ns
Reverse Recovery Charge	Q <sub>rr</sub>		--	30	--	nC

## Typical Characteristics Curves ( $T_J = 25^\circ\text{C}$ unless otherwise noted)

Fig.1 - Typical Output Characteristics

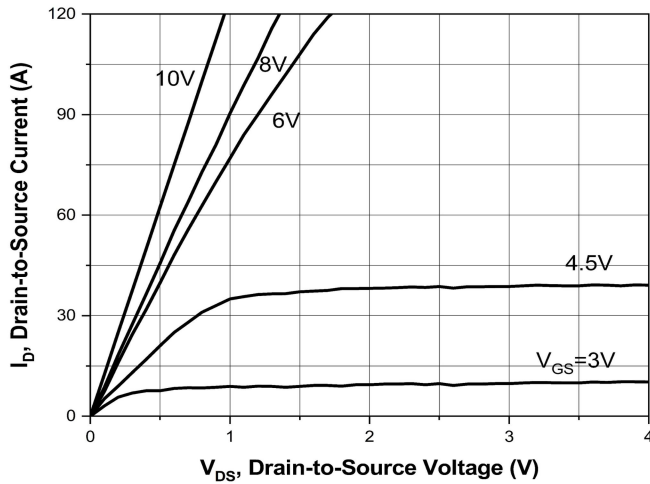


Fig.2 - Drain-to-Source Breakdown Voltage vs. Junction Temperature

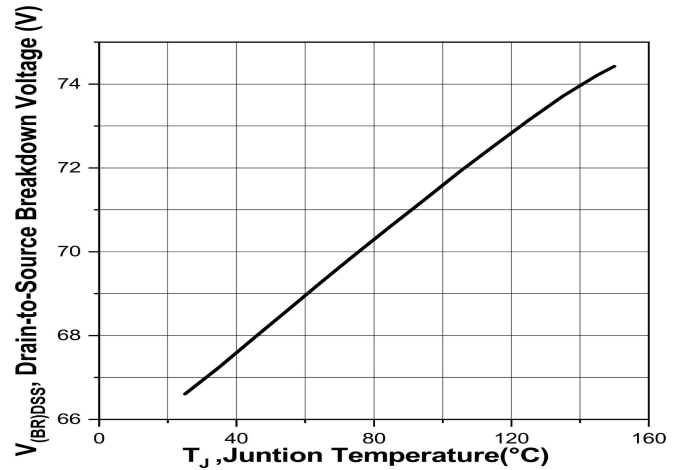


Fig.3 - R\_DS(on) vs. Junction Temperature

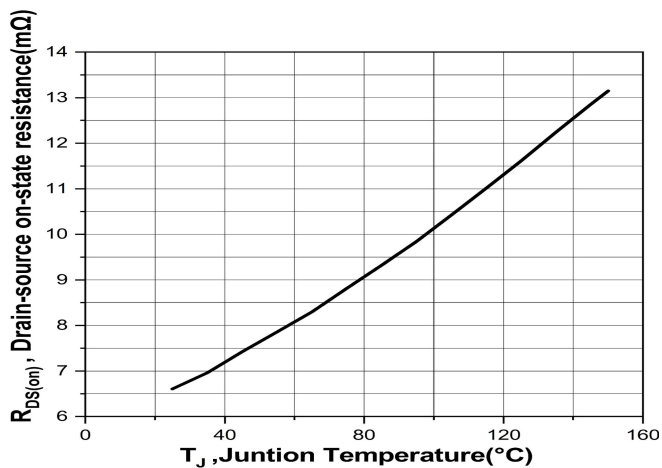


Fig.4 - V\_th vs. Junction Temperature

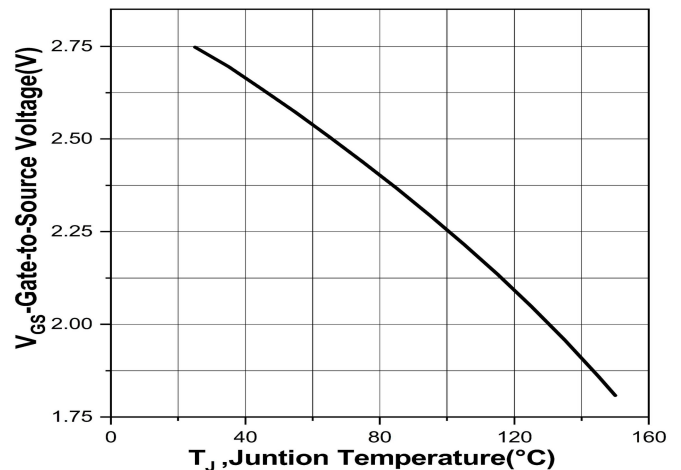


Fig.5 - Capacitance

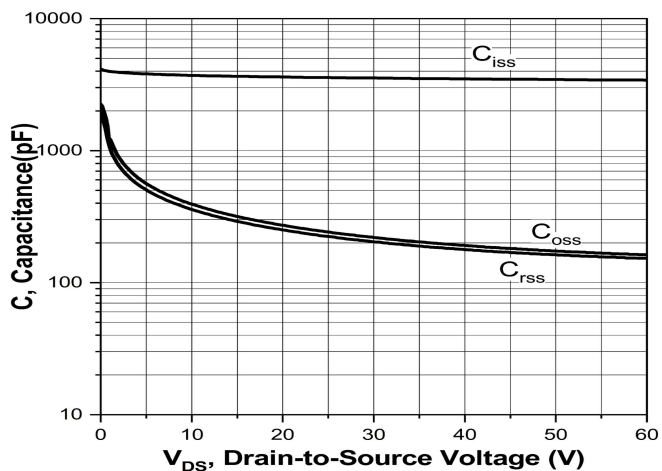
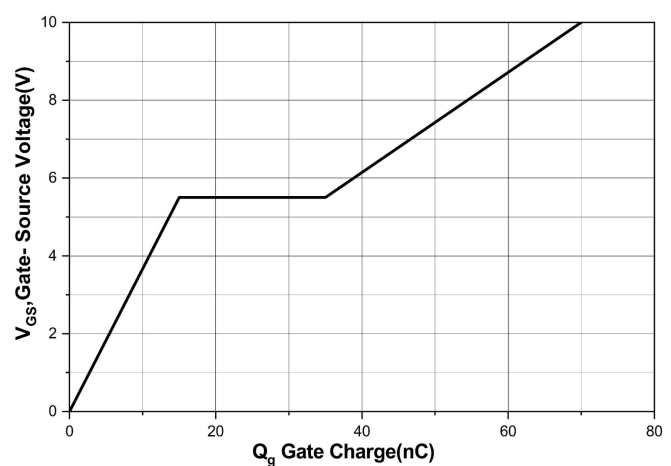


Fig.6 - Gate Charge



## Typical Characteristics Curves ( $T_J = 25^\circ\text{C}$ unless otherwise noted)

Fig.7 - Transfer Characteristics

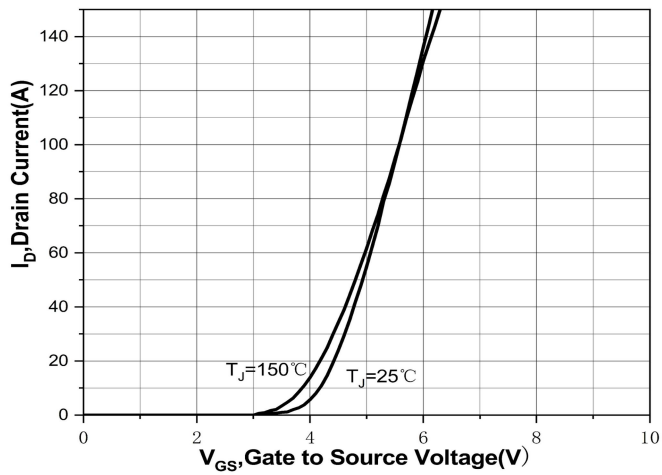
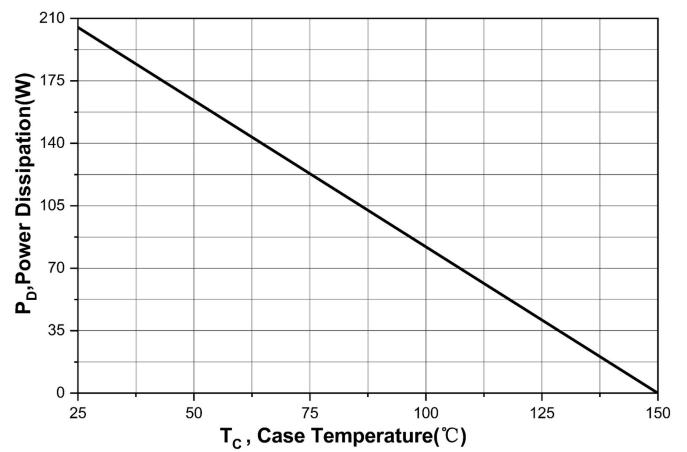
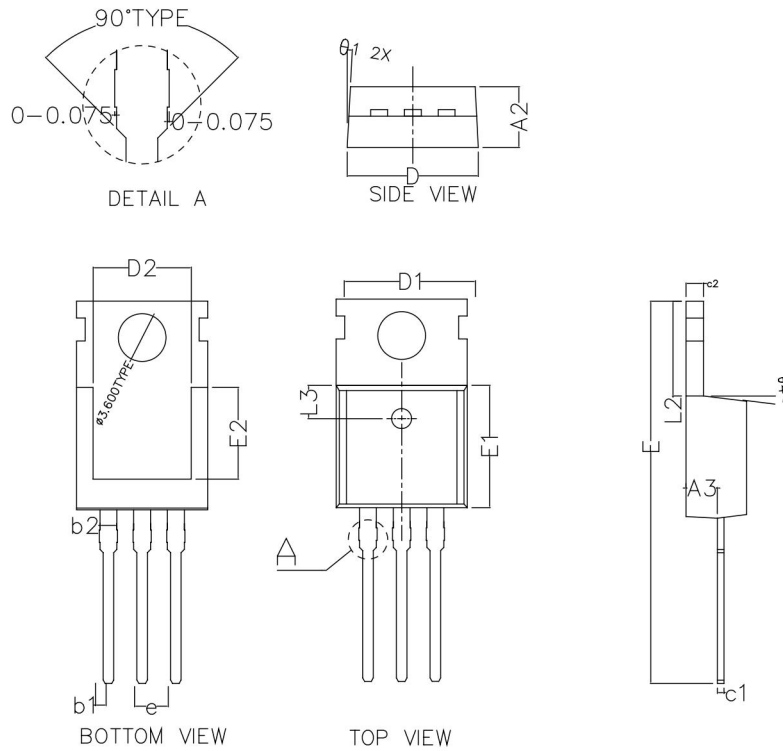


Fig.8 - Power Dissipation



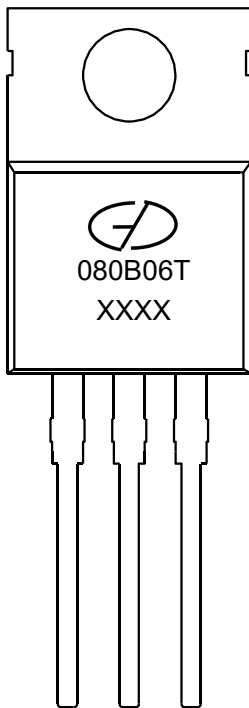
## Package Outline Dimensions (Unit: millimeters)

### TO-220AB




COMMON DIMENSIONS (UNITS OF MEASURE: IS mm)			
	MIN	NORMAL	MAX
A2	4.470	4.570	4.670
A3	2.300	2.350	2.400
b1	0.750	0.800	0.850
b2	1.27 TYPE		
c1	0.450	0.500	0.550
c2	1.250	1.300	1.380
▲ D	9.900	10.000	10.100
▲ D1	10.000TYPE		
▲ D2	8.000TYPE		
▲ E	28.660	28.860	29.060
▲ E1	9.000	9.100	9.200
▲ E2	7.000TYPE		
e	2.540TYPE		
L2	6.350	6.500	6.650
L3	2.50TYPE		
$\theta_1$	3° TYPE		
$\theta_2$	3° TYPE		
$\theta_3$	7° TYPE		
$\theta_4$	7° TYPE		

## Marking Outline



Part Name: GMN080B06T

1. Logo Mark: 
2. P/N Mark: 080B06T
3. Date Code: XXXX

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